PNP Epitaxial Planar Silicon Transistors



2SA1798

20V/8A Switching Applications

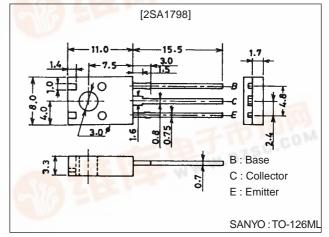
Features

- · Adoption of MBIT processes.
- · Low saturation voltage.
- · Fast switching speed.
- · Large current capacity.

Package Dimensions

unit:mm

2042A



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		-25	V
Collector-to-Emitter Voltage	VCEO		-20	V
Emitter-to-Base Voltage	V _{EBO}		-5	V
Collector Current	I _C		-8	Α
Colletor Current (Pulse)	I _{CP}	- LA CO- 14	-12	Α
Base Current	ΙB	AND PART LESS M	-1.5	Α
Collector Dissipation	PC		1.5	W
		Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg	- Co.	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Unit		
Farameter	Symbol		min	typ	max	Offic
Collector Cutoff Current	I _{CBO}	V _{CB} =-20V, I _E =0			-1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =-4V, I _C =0	39		-1	μA
DC Current Gain	h _{FE} 1	V _{CE} =-2V, I _C =-500mA	100*	M . D /	400*	
	h _{FE} 2	V _{CE} =-2V, I _C =-6A	60			
Gain-Bandwidth Product	fT	V _{CE} =-2V, I _C =-500mA		200		MHz
Output Capacitance	C _{ob}	V _{CB} =-10V, f=1MHz		85		pF

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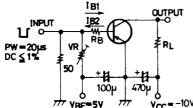
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters

Parameter	Symbol	Conditions		Unit		
Farameter	Symbol	Conditions		typ	max	Oill
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =-5A, I _B =-250mA		-220	-400	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =-5A, I _B =-250mA		-1	-1.3	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =-10μA, I _E =0	-25			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =-1mA, R _{BE} =∞	-20			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =-10μA, I _C =0	-5			V
Turn-ON Time	ton	See specified Test Circuit		30		ns
Storage Time	t _{stg}	See specified Test Circuit		200		ns
Fall Time	t _f	See specified Test Circuit		15		ns

 $[\]mbox{\ensuremath{*}}$: The 2SA1798 is classified by 500mA $\mbox{\ensuremath{h_{FE}}}$ as follows :

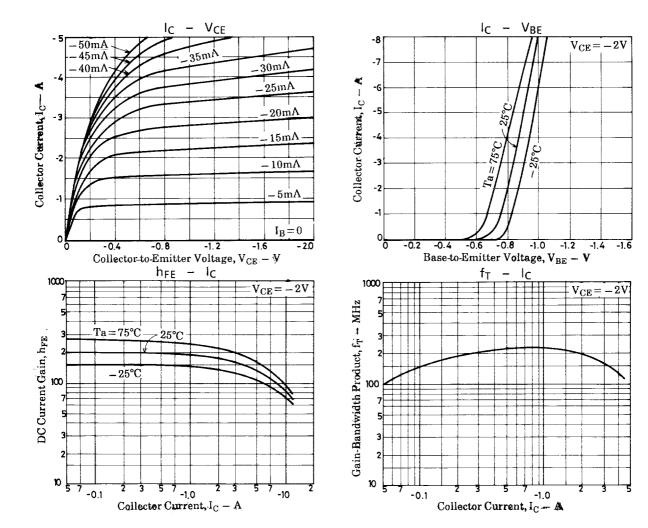
100	R	200	140	S	280	200	Т	400
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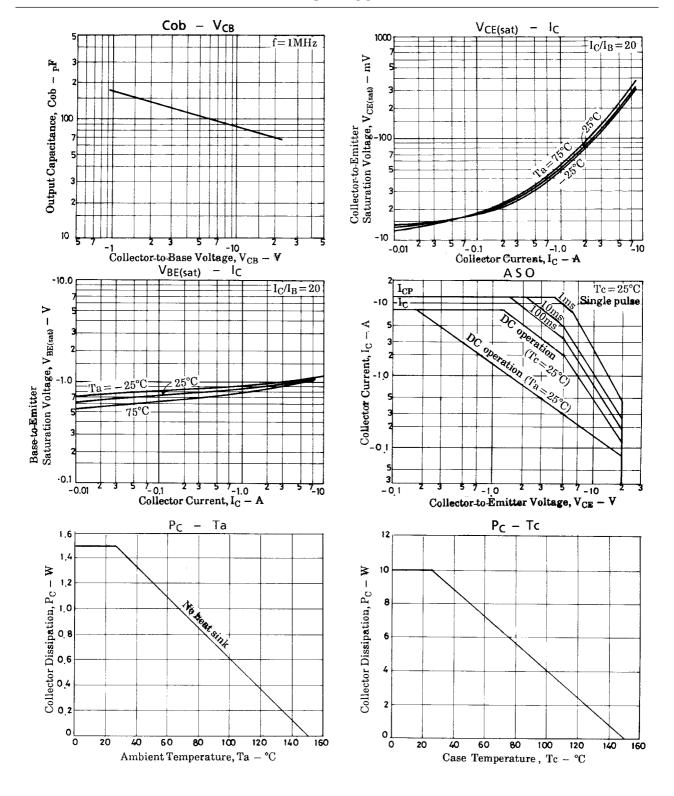
Switching Time Test Circuit



 $20I_{B1} = -20I_{B2} = I_C = -5A$

Unit (resistance : Ω , capacitance : F)





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